

200-mA Low-Noise, High-PSRR, Negative-Output, Low-Dropout Linear Regulators

Check for Samples: TPS72301-Q1, TPS72325-Q1

FEATURES

- Qualified for Automotive Applications
- Ultralow Noise: 60 µV_{RMS} Typical
- High PSRR: 65 dB Typical at 1kHz
- Low Dropout Voltage: 280 mV Typical at 200 mA, 2.5 V
- Available in –2.5 V and Adjustable (–1.2 V to –10 V) Versions
- Stable With a 2.2-µF Ceramic Output Capacitor
- Less Than 2-µA Typical Quiescent Current in Shutdown Mode
- 2% Overall Accuracy (Line, Load, Temperature)
- Thermal and Overcurrent Protection
- SOT23-5 (DBV) Package
- Operating Junction Temperature Range: –40°C to 125°C

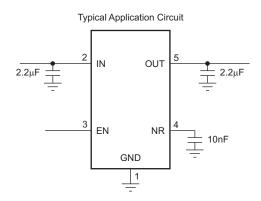
APPLICATIONS

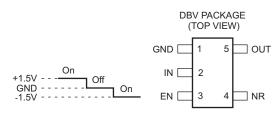
- Optical Drives
- Optical Networking
- Noise-Sensitive Circuitry
- GaAs FET Gate Bias
- Video Amplifiers

DESCRIPTION

The TPS723xx-Q1 family of low-dropout (LDO) negative voltage regulators offers an ideal combination of features to support low-noise applications. This device is capable of operating with input voltages from -10 V to -2.7 V. The TPS72325-Q1 regulator is stable with small, low-cost ceramic capacitors, and includes enable (EN) and noisereduction (NR) functions. Internal detection and shutdown logic provide thermal short-circuit and overcurrent protection. High PSRR (65 dB at 1 kHz) and low noise (60 µV_{RMS}) make the TPS723xx-Q1 ideal for low-noise applications.

The TPS723xx-Q1 uses a precision voltage reference to achieve 2% overall accuracy over load, line, and temperature variations. Available in a small SOT23-5 package, the TPS723xx-Q1 specification covers the full temperature range of -40°C to 125°C.





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TPS72301-Q1 TPS72325-Q1

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STRUMENTS

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This integrated circuit can be damaged by ESD. Texas Instruments recommends that all integrated circuits be handled with appropriate precautions. Failure to observe proper handling and installation procedures can cause damage.

ESD damage can range from subtle performance degradation to complete device failure. Precision integrated circuits may be more susceptible to damage because very small parametric changes could cause the device not to meet its published specifications.

ORDERING INFORMATION⁽¹⁾ ⁽²⁾

PRODUCT	V _{OUT} ⁽²⁾	TOP-SIDE MARKING		
TPS72301QDBVRQ1	Adjustable output voltage	PPHQ		
TPS72325QDBVRQ1	Nominal output voltage = 2.5 V	PSBQ		

(1) For the most current package and ordering information, see the Package Option Addendum at the end of this document, or see the TI Web site at www.ti.com.

(2) Output voltages from -1.2 V to -9 V in 100-mV increments are available. Minimum order quantities apply; contact factory for details and availability.

ABSOLUTE MAXIMUM RATINGS⁽¹⁾ ⁽²⁾

Over operating temperature range, unless otherwise noted.

		VALUE	UNITS		
Input voltage rar	nge, V _{IN}	-11 to 0.3	V		
Noise reduction	pin voltage range, V _{NR}	-11 to 5.5	V		
Enable voltage r	ange, V _{EN}	-V _{IN} to 5.5	V		
Output current, I	OUT	Internally limited			
Output short-circ	cuit duration	Indefinite			
Continuous total	power dissipation, P _D	See Power Dissipation Ratings table			
Junction tempera	ature range, T _J	-55 to 150	°C		
Storage tempera	ature range, T _{stg}	-65 to 150	°C		
Latch-up perform	nance meets 100 mA per AEC-Q100 Class I	100	mA		
	Human-body model	2000	kV		
ESD ratings	Machine model	200	V		
	Charged-device model	500	V		

(1) Stresses beyond those listed under *Absolute Maximum Ratings* may cause permanent damage to the device. These are stress ratings only, and functional operation of the device at these or any other conditions beyond those indicated under *Recommended Operating Conditions* is not implied. Exposure to absolute-maximum-rated conditions for extended periods may affect device reliability.

(2) All voltage values are with respect to network ground terminal.

POWER DISSIPATION RATINGS

BOARD	PACKAGE	R _{θJC}	R _{0JA}	DERATING FACTOR ABOVE T _A = 25°C	T _A ≤ 25°C POWER RATING	T _A = 70°C POWER RATING	T _A = 85°C POWER RATING
Low-K ⁽¹⁾	DBV	64°C / W	255°C / W	3.9 mW / °C	390 mW	215 mW	155 mW
High-K ⁽²⁾	DBV	64°C / W	180°C / W	5.6 mW / °C	560 mW	310 mW	225 mW

(1) The JEDEC low-K (1s) board design used to derive this data was a 3-inch × 3- inch (7,62-cm × 7,62-cm), two-layer board with 2-ounce (0.071-mm thick) copper traces on top of the board.

(2) The JEDEC High-K (2s2p) board design used to derive this data was a 3 inch x 3 inch (7,62-cm x 7,62-cm), multilayer board with 1-ounce (0.035-mm thick) internal power and ground planes and 2-ounce (0.071-mm thick) copper traces on the top and bottom of the board.



ELECTRICAL CHARACTERISTICS

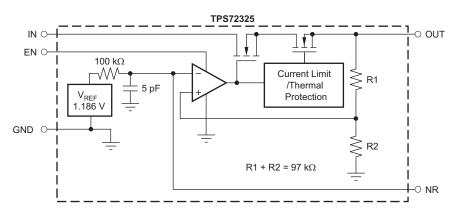
Over operating junction temperature range, $V_{IN} = V_{OUTnom} - 0.5V$, $I_{OUT} = 1mA$, $V_{EN} = 1.5V$, $C_{OUT} = 2.2\mu$ F, and $C_{NR} = 0.01\mu$ F, unless otherwise noted. Typical values are at $T_J = 25^{\circ}$ C.

				TP					
	PARAMETER		TEST CONDITIONS	MIN	MIN TYP MAX		UNITS		
V _{IN}	Input voltage range ⁽¹⁾			-10		-2.7	V		
		Nominal	T _J = 25°C	-1		1	%		
V _{OUT}	Accuracy	TPS723xx-Q1 versus V _{IN} / I _{OUT} / T	$-10V \le V_{IN} \le V_{OUT} - 0.5V,$ $10 \ \mu A \le I_{OUT} \le 200 \ mA$	-2	±1	2	%		
V _{OUT} % / V _{IN}	Line regulation		$-10 \text{ V} \leq \text{V}_{\text{IN}} \leq \text{V}_{\text{OUT(nom)}} - 0.5 \text{ V}$		0.04		% / V		
V _{OUT} % / I _{OUT}	Load regulation		0 mA ≤ I _{OUT} ≤ 200 mA		0.002		% / mA		
V _{DO}	Dropout voltage at V _{OUT} =	0.96 × V _{OUTnom}	I _{OUT} = 200 mA		280	500	mV		
I _{CL}	Current limit		$V_{OUT} = 0.85 \times V_{OUT(nom)}$	300	550	800	mA		
			$I_{OUT} = 0 \text{ mA } (I_Q),$ -10 V ≤ V _{IN} ≤ V _{OUT} - 0.5 V		130	200			
I _{GND}	Ground pin current		I_{OUT} = 200 mA, -10 V ≤ V _{IN} ≤ V _{OUT} - 0.5 V		350	500	- μΑ		
I _{SHDN}	Shutdown ground pin curr	ent	$-0.4 V \le V_{EN} \le 0.4 V,$ $-10V \le V_{IN} \le V_{OUT} - 0.5 V$		0.1	2	μA		
	Description	•-	I_{OUT} = 200 mA, 1 kHz, C_{IN} = C_{OUT} = 10 µF		65		- ID		
PSRR	Power-supply rejection rat	10	I_{OUT} = 200 mA, 10 kHz, C_{IN} = C_{OUT} = 10 µF		48		- dB		
V _n	Output noise voltage		$\label{eq:COUT} \begin{split} C_{OUT} = 10 \ \mu\text{F}, \ 10 \ \text{Hz} \ \text{to} \ 100 \ \text{kHz}, \\ I_{OUT} = 200 \ \text{mA} \end{split}$		60		μV _{RMS}		
t _{STR}	Startup time		$\label{eq:Vout} \begin{array}{l} V_{OUT} = -2.5 \ V, \ C_{OUT} = 1 \ \muF, \\ R_{L} = 25 \ \Omega \end{array}$		1		ms		
V _{EN(HI)}	Enable threshold positive			1.5			V		
V _{EN(LO)}	Enable threshold negative					-1.5	V		
V _{DIS(HI)}	Disable threshold positive					0.4	V		
V _{DIS(LO)}	Disable threshold negative			-0.4			V		
I _{EN}	Enable pin current		$\begin{array}{c} -10 \ V \leq V_{\rm IN} \leq V_{\rm OUT} \ -0.5 \ V, \\ -10 \ V \leq V_{\rm EN} \leq \pm 3.5 \ V \end{array}$		0.1	2	μA		
-		roturo.	Shutdown, temperature increasing		165		- °C		
T _{SD}	Thermal shutdown temper	aure	Reset, temperature decreasing		145	<u> </u>			
TJ	Operating junction temper	ature		-40		125	°C		

(1) Maximum $V_{IN} = (V_{OUT} - V_{DO})$ or -2.7 V, whichever is more negative.



FUNCTIONAL BLOCK DIAGRAM



TERMINAL FUNCTIONS

TERMINAL		
NAME	NO.	DESCRIPTION
GND	1	Ground
IN	2	Input supply
EN	3	Bipolar enable pin. Driving this pin above the positive enable threshold or below the negative enable threshold turns on the regulator. Driving this pin below the positive disable threshold and above the negative disable threshold puts the regulator into shutdown mode.
NR	4	Fixed-voltage versions only. Connecting an external capacitor between this pin and ground bypasses noise generated by the internal band gap. This configuration allows output noise to be reduced to very low levels.
OUT	5	Regulated output voltage. The device requires the connection of a small 2.2- μ F ceramic capacitor from this pin to GND to ensure stability.

TPS72301-Q1 TPS72325-Q1

SLVSAJ4B-SEPTEMBER 2010-REVISED SEPTEMBER 2012

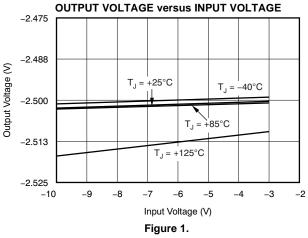
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TYPICAL CHARACTERISTICS

TPS723xx-Q1 at $V_{IN} = V_{OUTnom} - 0.5 \text{ V}$, $I_{OUT} = 1 \text{ mA}$, $V_{EN} = 1.5 \text{ V}$, $C_{OUT} = 2.2 \mu\text{F}$, and $C_{NR} = 0.01 \mu\text{F}$, unless otherwise noted.



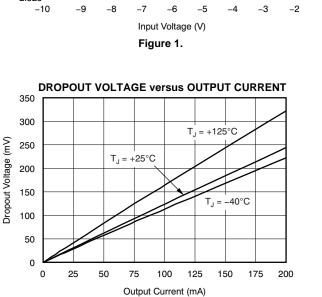
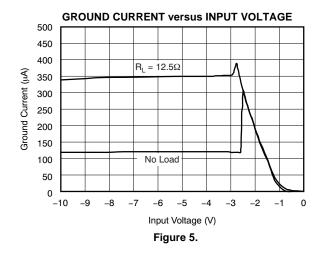
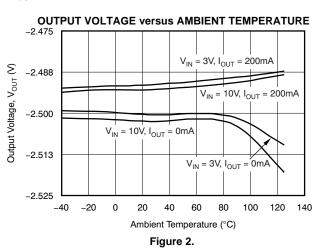
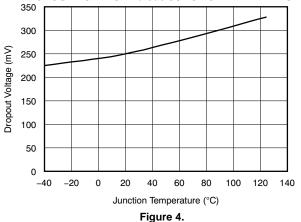


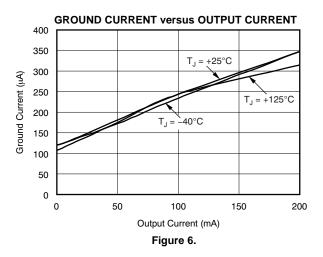
Figure 3.





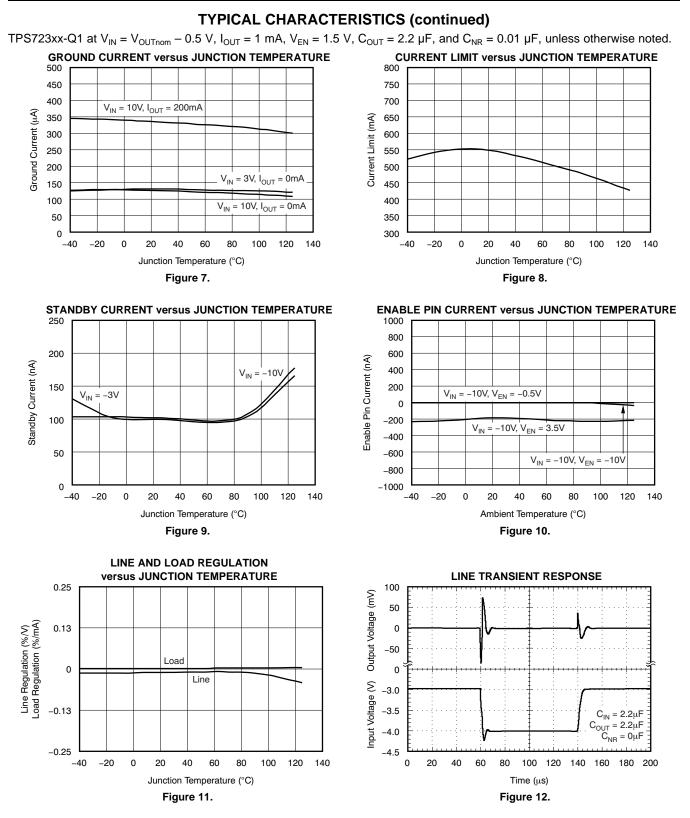
TPS723xx-Q1 DROPOUT VOLTAGE versus JUNCTION TEMPERATURE





5

TPS72301-Q1 TPS72325-Q1 SLVSAJ4B – SEPTEMBER 2010 – REVISED SEPTEMBER 2012



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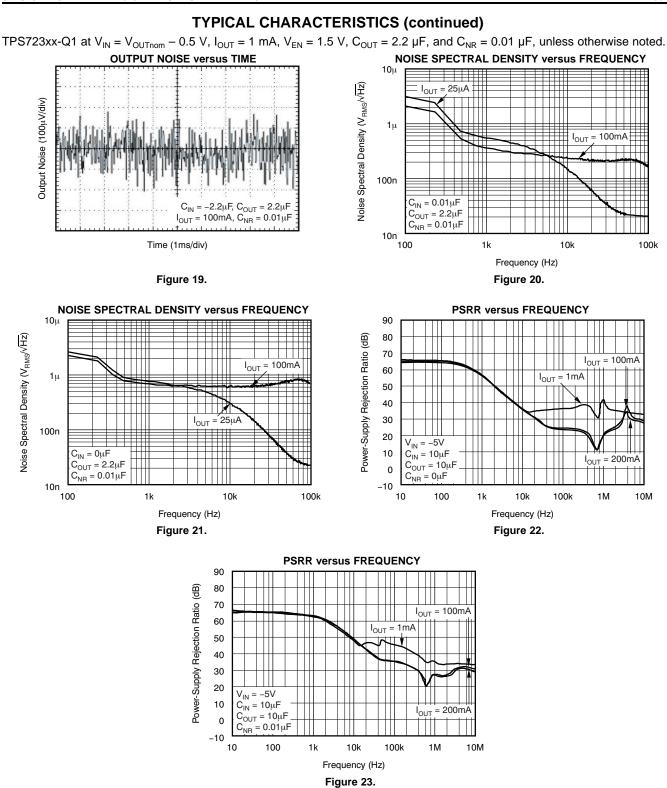


TPS72301-Q1 TPS72325-Q1

SLVSAJ4B-SEPTEMBER 2010-REVISED SEPTEMBER 2012 www.ti.com **TYPICAL CHARACTERISTICS (continued)** TPS723xx-Q1 at $V_{IN} = V_{OUTnom} - 0.5 \text{ V}$, $I_{OUT} = 1 \text{ mA}$, $V_{EN} = 1.5 \text{ V}$, $C_{OUT} = 2.2 \mu\text{F}$, and $C_{NR} = 0.01 \mu\text{F}$, unless otherwise noted. LOAD TRANSIENT RESPONSE LOAD TRANSIENT RESPONSE 100 100 $\Delta V_{OUT},$ Change In Output Voltage (mV) Current Load (mA) 0 0 AV_{OUT}, Change In Output Voltage (mV) Current Load (mA) 0 0 -100 -100 $C_{IN} = 2.2 \mu F$ C_{IN} = 2.2μF $C_{OUT} = 2.2 \mu F$ $C_{NR} = 0 \mu F$ $C_{OUT} = 2.2 \mu F$ $C_{NR} = 0 \mu F$ -200 -200 0 20 60 80 100 120 140 160 180 200 0 20 60 80 100 120 140 160 180 200 40 40 Time (µs) Time (µs) Figure 13. Figure 14. START-UP RESPONSE START-UP RESPONSE Output Voltage (mV) Output Voltage (mV) 0 1 2 0 Input Voltage (V) nput Voltage (V) 1 $C_{IN} = 2.2 \mu F$ C_{IN} = 2.2μF 2 C_{OUT} = 2.2µF $C_{OUT} = 2.2 \mu F$ $I_{OUT} = 50mA$ $C_{NR} = 0.01 \mu F$ $I_{OUT} = 50 \text{mA}$ $C_{NR} = 0 \mu \text{F}$ 3 0 0.1 0.2 0.3 0.4 0.5 0.6 0.7 0.8 0.9 1.0 0 0.1 0.2 0.3 0.4 0.5 0.6 0.7 0.8 0.9 1.0 Time (ms) Time (ms) Figure 16. Figure 15. TOTAL NOISE versus C_{NR} POWER UP AND POWER DOWN (10Hz to 100kHz) 0.5 250 $C_{IN} = 2.2 \mu F$ $C_{OUT} = 2.2 \mu F$, $I_{OUT} = 100 m A$ V_{OUT} 0 200 $C_{OUT} = 10\mu F$, $I_{OUT} = 100 mA$ -0.5 Total Noise (µV_{RMS}) -1.0 150 -1.5 $I_{OUT} = 25 \text{mÅ}$ $C_{OUT} = 2.2 \mu F$, 100 -20 $C_{IN} = 2.2 \mu F$ -2.5 $C_{OUT} = 2.2 \mu F$ 50 -----I_{OUT} = 50mA -3.0 $C_{OUT} = 10\mu F$, $I_{OUT} = 25mA$ C_{NR} = 0μF Î. E. HIIII -3.5 0 0 2 3 5 6 7 8 9 10 10 100 1k 10k 100k 1 4 Time (ms) C_{NR} (pF) Figure 17. Figure 18.

Voltage (V)

TPS72301-Q1 TPS72325-Q1 SLVSAJ4B-SEPTEMBER 2010-REVISED SEPTEMBER 2012



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APPLICATION INFORMATION

DEVICE OPERATION

The TPS723xx-Q1 is a low-dropout negative linear voltage regulator with a rated current of 200 mA. It features very low noise and high power-supply rejection ratio (PSRR), making it ideal for high-sensitivity analog and RF applications. A shutdown mode is available, reducing ground current to 2 μ A maximum over temperature and process. The TPS723xx-Q1 comes in a small SOT23 package, specified over a -40°C to 125°C junction-temperature range.

ENABLE

The enable pin is active above 1.5 V and below -1.5 V, allowing control by a standard TTL signal or by connection to V_I if not used. Driving the pin to GND turns off most internal circuitry, putting the TPS723xx-Q1 into shutdown mode, drawing 2-µA maximum ground current.

CAPACITOR SELECTION FOR STABILITY

Use appropriate input and output capacitors for the intended application. The TPS723xx-Q1 only requires the use of a 2.2-µF ceramic output capacitor for stable operation. Both the capacitor value and ESR affect stability, output noise, PSRR, and transient response. For typical applications, a 2.2-µF ceramic output capacitor located close to the regulator is sufficient.

OUTPUT NOISE

Without external bypassing, output noise of the TPS723xx-Q1 from 10 Hz to 100 kHz is 200 μV_{RMS} typical. The dominant contributor to output noise is the internal band-gap reference. Adding an external 0.01- μ F capacitor to ground reduces the noise to 60 μV_{RMS} . To achieve best noise performance, use appropriate low-ESR capacitors for bypassing noise at the NR and OUT pins. See Figure 18 in the Typical Characteristics section.

POWER-SUPPLY REJECTION

The TPS723xx-Q1 offers a very high PSRR for applications with noisy input sources or highly sensitive output supply lines. For best PSRR, use high-quality input and output capacitors.

CURRENT LIMIT

The TPS723xx-Q1 has internal circuitry that monitors and limits output current to protect the regulator from damage under all load conditions. When output current reaches the output-current limit (550 mA typical), protection circuitry turns on, reducing output voltage to ensure that current does not increase. See Figure 8 in the Typical Characteristics section.

Do not drive the output more than 0.3 V above the input. Doing so biases the body diode in the pass FET, allowing current to flow from the output to the input. The device does not limit this current. If this condition is likely, take care to limit the reverse current externally.

THERMAL PROTECTION

As protection from damage due to excessive junction temperatures, the TPS723xx-Q1 has internal protection circuitry. When junction temperature reaches approximately 165°C, the output device turns off. After the device has cooled by about 20°C, the output device turns on, allowing normal operation. For reliable operation, design is for worst-case junction temperature of \leq 125°C, taking into account worst-case ambient temperature and load conditions.

ADJUSTABLE VOLTAGE APPLICATIONS

The TPS72301-Q1 allows designers to specify any output voltage from -10 V to -1.2 V. As shown in the application circuit in Figure 24, use of an external resistor divider scales the output voltage (V_{OUT}) to the reference voltage. For best accuracy, use precision resistors for R1 and R2. Use the equations in Figure 24 to determine the values for the resistor divider.

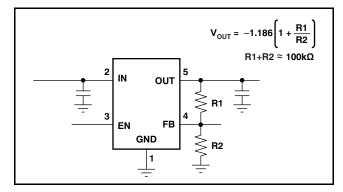


Figure 24. TPS72301-Q1 Adjustable LDO Regulator Programming



11-Apr-2013

PACKAGING INFORMATION

Orderable Device	Status	Package Type	Package	Pins	Package	Eco Plan	Lead/Ball Finish	MSL Peak Temp	Op Temp (°C)	Top-Side Markings	Samples
	(1)		Drawing		Qty	(2)		(3)		(4)	
TPS72301QDBVRQ1	ACTIVE	SOT-23	DBV	5	3000	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM	-40 to 125	PPHQ	Samples
TPS72325QDBVRQ1	ACTIVE	SOT-23	DBV	5	3000	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM	-40 to 125	PSBQ	Samples

⁽¹⁾ The marketing status values are defined as follows:

ACTIVE: Product device recommended for new designs.

LIFEBUY: TI has announced that the device will be discontinued, and a lifetime-buy period is in effect.

NRND: Not recommended for new designs. Device is in production to support existing customers, but TI does not recommend using this part in a new design.

PREVIEW: Device has been announced but is not in production. Samples may or may not be available.

OBSOLETE: TI has discontinued the production of the device.

(2) Eco Plan - The planned eco-friendly classification: Pb-Free (RoHS), Pb-Free (RoHS Exempt), or Green (RoHS & no Sb/Br) - please check http://www.ti.com/productcontent for the latest availability information and additional product content details.

TBD: The Pb-Free/Green conversion plan has not been defined.

Pb-Free (RoHS): TI's terms "Lead-Free" or "Pb-Free" mean semiconductor products that are compatible with the current RoHS requirements for all 6 substances, including the requirement that lead not exceed 0.1% by weight in homogeneous materials. Where designed to be soldered at high temperatures, TI Pb-Free products are suitable for use in specified lead-free processes. **Pb-Free (RoHS Exempt):** This component has a RoHS exemption for either 1) lead-based flip-chip solder bumps used between the die and package, or 2) lead-based die adhesive used between

the die and leadframe. The component is otherwise considered Pb-Free (RoHS compatible) as defined above.

Green (RoHS & no Sb/Br): TI defines "Green" to mean Pb-Free (RoHS compatible), and free of Bromine (Br) and Antimony (Sb) based flame retardants (Br or Sb do not exceed 0.1% by weight in homogeneous material)

⁽³⁾ MSL, Peak Temp. -- The Moisture Sensitivity Level rating according to the JEDEC industry standard classifications, and peak solder temperature.

(4) Multiple Top-Side Markings will be inside parentheses. Only one Top-Side Marking contained in parentheses and separated by a "~" will appear on a device. If a line is indented then it is a continuation of the previous line and the two combined represent the entire Top-Side Marking for that device.

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OTHER QUALIFIED VERSIONS OF TPS72301-Q1, TPS72325-Q1 :



PACKAGE OPTION ADDENDUM

11-Apr-2013

• Catalog: TPS72301, TPS72325

NOTE: Qualified Version Definitions:

Catalog - TI's standard catalog product

PACKAGE MATERIALS INFORMATION

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TAPE AND REEL INFORMATION

REEL DIMENSIONS

TEXAS INSTRUMENTS





TAPE AND REEL INFORMATION

TAPE DIMENSIONS



A0	Dimension designed to accommodate the component width
B0	Dimension designed to accommodate the component length
K0	Dimension designed to accommodate the component thickness
W	Overall width of the carrier tape
P1	Pitch between successive cavity centers

*All dimensions are nominal												
Device	Package Type	Package Drawing		SPQ	Reel Diameter (mm)	Reel Width W1 (mm)	A0 (mm)	B0 (mm)	K0 (mm)	P1 (mm)	W (mm)	Pin1 Quadrant
TPS72301QDBVRQ1	SOT-23	DBV	5	3000	179.0	8.4	3.2	3.2	1.4	4.0	8.0	Q3
TPS72325QDBVRQ1	SOT-23	DBV	5	3000	179.0	8.4	3.2	3.2	1.4	4.0	8.0	Q3

Pack Materials-Page 1

TEXAS INSTRUMENTS

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PACKAGE MATERIALS INFORMATION

28-Aug-2012



*All dimensions are nominal

Device	Package Type	Package Drawing	Pins	SPQ	Length (mm)	Width (mm)	Height (mm)
TPS72301QDBVRQ1	SOT-23	DBV	5	3000	203.0	203.0	35.0
TPS72325QDBVRQ1	SOT-23	DBV	5	3000	203.0	203.0	35.0

DBV (R-PDSO-G5)

PLASTIC SMALL-OUTLINE PACKAGE



- A. All linear dimensions are in millimeters.
 - This drawing is subject to change without notice. Β.
 - Body dimensions do not include mold flash or protrusion. Mold flash and protrusion shall not exceed 0.15 per side. C.
 - D. Falls within JEDEC MO-178 Variation AA.



DBV (R-PDSO-G5)

PLASTIC SMALL OUTLINE



NOTES:

A. All linear dimensions are in millimeters.B. This drawing is subject to change without notice.

- C. Customers should place a note on the circuit board fabrication drawing not to alter the center solder mask defined pad.
- D. Publication IPC-7351 is recommended for alternate designs.
- E. Laser cutting apertures with trapezoidal walls and also rounding corners will offer better paste release. Customers should contact their board assembly site for stencil design recommendations. Example stencil design based on a 50% volumetric metal load solder paste. Refer to IPC-7525 for other stencil recommendations.



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Only those TI components which TI has specifically designated as military grade or "enhanced plastic" are designed and intended for use in military/aerospace applications or environments. Buyer acknowledges and agrees that any military or aerospace use of TI components which have *not* been so designated is solely at the Buyer's risk, and that Buyer is solely responsible for compliance with all legal and regulatory requirements in connection with such use.

TI has specifically designated certain components as meeting ISO/TS16949 requirements, mainly for automotive use. In any case of use of non-designated products, TI will not be responsible for any failure to meet ISO/TS16949.

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